

10.3Gb/s XFP Transceiver

APX85B30xDL03





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ATOP's APX85B30xDL03 Small Form Factor 10Gb/s XFP transceivers are compatible with XFP MSA Specification. It is designed for use in 10G-Gigabit links up to 300m of OM3. Digital diagnostics functions are available via a 2-wire serial interface, as specified in the XFP MSA.

Product Features

- ✓ Duplex LC connector
- √ Hot-pluggable XFP footprint
- √ 850nm VCSEL laser
- \checkmark RoHS compliant and Lead Free
- ✓ Distance up to 300m on 50/125um MMF
- ✓ Metal enclosure for lower EMI
- √ +3.3V power supply and power dissipation <1.5W
 </p>
- ✓ XFP MSA INF-8077I Compliant
- √ Compliant with IEEE 802.3ae

Applications

- ✓ 10GBASE-SR/SW
- √ 10G Fibre Channel



Product Selection

Part Number	Operating Case temperature	DDMI
APX85B30CDL03	Commercial(0~70°C)	Yes
APX85B30IDL03	Industrial(-40~85°C)	Yes



Regulatory Compliance

- ESD to the Electrical PINs: compatible with MIL-STD-883 Method 3015
- ESD to the Duplex LC Receptacle: compatible with EN 61000-4-2
- Immunity compatible with EN 61000-4-3
- EMI compatible with FCC Part 15 Class B
- Laser Eye Safety compatible with FDA 21CFR 1040.10 and 1040.11 IEC 60950, IEC 60825-1,2
- RoHS compliant with RoHS 2.0(2015/863/EU)-Amending

Pin Descriptions

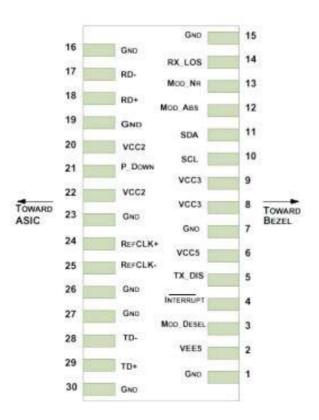
Pin	Symbol	Name	Ref.
1	GND	Module Ground	
2	VEE5	Optional-5.2 Power Supply-not required	
3	MOD_DESEL	Module De-select; When held low allows the module to respond to 2-wire serial interface. LVTTL-I	
4	/INTERRUPT	Interrupt; Indicates presence of an important condition which can be read via the 2-wire serial interface. LVTTL-O	2
5	TX_DIS	Transmitter Disable. Logic 1 indicates laser output disabled, LVTTL-I	
6	VCC5	+5V Power Supply	
7	GND	Module Ground	1
8	VCC3	+3.3V Power Supply	
9	VCC3	+3.3V Power Supply	
10	SCL	2-Wire Serial Interface Clock. LVTTL-I	2
11	SDA	2-Wire Serial Interface Data Line. LVTTL-I/O	2
12	MOD_ Abs	Indicates Module is not present. Grounded in the Module. LVTTL-O	2
13	MOD_NR	Module Not Ready; Indicating Module Operational Fault. Open-collector. LVTTL-O	2
14	RX_LOS	Loss of Signal indication. Logic 1 indicates loss of Signal. Open-collector. LVTTL-O	2
15	GND	Module Ground	1
16	GND	Module Ground	1
17	RD-	Receiver Inverted Data Output. CML-O	
18	RD+	Receiver Non-Inverted Data Output. CML-O	
19	GND	Module Ground	1
20	VCC2	+1.8V Power Supply (Not required).	3
21	P_DOWN/RST	Power down; When high, requires the module to limit power consumption to 1.5W or below. 2-Wire serial interface must be functional in the low power mode. LVTTL-I Reset; The falling edge initiates a complete reset of the module including the 2-wire serial interface, equivalent to a power cycle. LVTTL-I	



22	VCC2	+1.8V Power Supply (Not required)	3
23	GND	Module Ground	1
24	REFCLK+	Reference Clock (Not required)	
25	REFCLK-	Reference Clock (Not required)	
26	GND	Module Ground	1
27	GND	Module Ground	1
28	TD-	Transmitter Inverted Data Input. CML-I	
29	TD+	Transmitter Non-Inverted Data Input. CML-I	
30	GND	Module Ground	1

Note

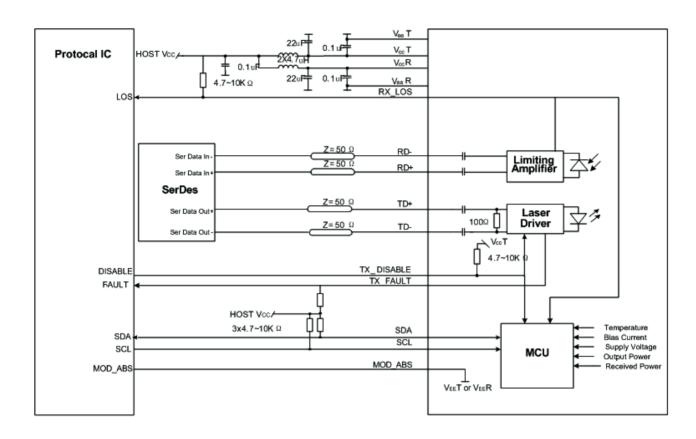
- 1. Module ground pins GND are isolated from the module case and chassis ground within the module.
- 2. Open collector, Should be pulled up with 4.7K-10Kohms to a voltage between 3.15V and 3.6V on the host board.
- 3. The pins are open within module.



Pin-out of Connector Block on Host Board



Recommend Circuit Schematic



Absolute Maximum Ratings

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Maximum Supply Voltage	Vcc3	-0.5		+4.0	V	
Storage Temperature	TS	-40		+85	°C	
Operating Humidity	RH	0		85	%	



Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Power Supply Voltage	Vcc3	3.13	3.30	3.47	V	
Power Supply Current	lcc3			430	mA	
	Tc	0		+70	°C	Commercial
Case Operating Temperature	TI	-40		+85	°C	Industrial
Bit Rate	BR		10.3		Gbps	
9/125um G.652 SMF	Lmax			300	m	

Electrical Characteristics

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Transmitter						
Input differential impedance	Rin	80	100	120	Ω	1
Differential data input swing	Vin, pp	120		850	mV	
TX Disable-High		Vcc – 0.8		Vcc	V	
TX Disable-Low		Vee		Vee+ 0.8	V	
TX Fault-High		Vcc-0.8		Vcc	V	
TX Fault-Low		Vee		Vee+0.8	V	
Receiver						
Differential data output swing	Vout, pp	300		850	mV	2
Data output rise time	Tr	30			ps	3
Data output fall time	Tf	30			ps	3
LOS-High		Vcc – 0.8		Vcc	V	
LOS-Low		Vee		Vee+0.8	V	

- Notes: 1. AC coupled.
- Into 100 ohm differential termination.
 20 80 %

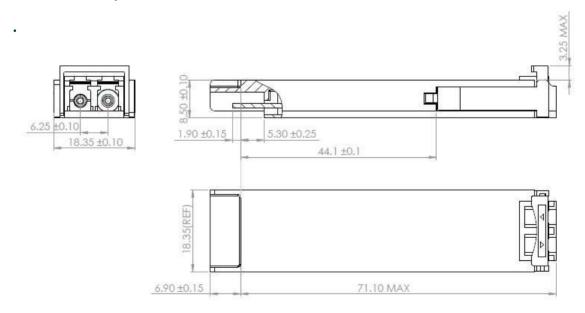


Optical Characteristics

Symbol	Min	Тур	Max	Unit	Ref.
РО	-5		-1	dBm	
λ	840		860	nm	
Δλ			0.45	nm	
ER	3			dB	
TDP			3.9	dB	
Poff			-30	dBm	
SENS			-11.1	dBm	1,2
	-1			dBm	
λC	840		860	nm	
LOSD	-		-13	dBm	
LOSA	-30			dBm	
	0.5			dB	
	PO λ Δλ ER TDP Poff SENS	PO -5 λ 840 Δλ ER 3 TDP Poff SENS -1 λC 840 LOSD - LOSA -30	PO -5 λ 840 Δλ ER 3 TDP Poff SENS -1 λC 840 LOSD - LOSA -30	PO -5 -1 λ 840 860 Δλ 0.45 ER 3 TDP 3.9 Poff -30 SENS -11.1 λC 840 860 LOSD13 LOSA -30	PO -5 -1 dBm λ 840 860 nm Δλ 0.45 nm ER 3 dB TDP 3.9 dB Poff -30 dBm SENS -11.1 dBm λC 840 860 nm LOSD13 dBm LOSA -30 dBm

- 1.Measured with conformance signals defined in FC-PI-2 Rev. 10.0 specifications. 2.Measured with PRBS 2 $^{-31}$ -1 at 10 $^{-12}$ BER.

Mechanical Specifications

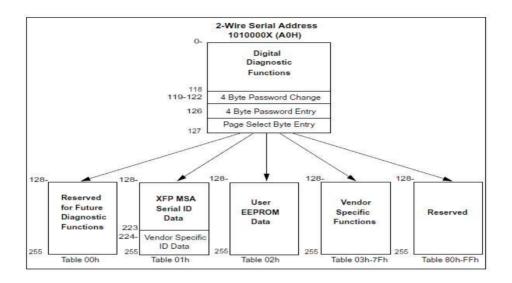


APX85B30xDL03(dimensions are in mm)



EEPROM Information

• EEPROM memory map specific data field description is as below:



Digital Diagnostic Monitoring Interface

Five transceiver parameter values are monitored. The following table defines the monitored parameter's accuracy.

Parameter	Range	Accuracy	Calibration	
Temperature	0 to +70°C (C)	. 205		
	-40 to +85°C (I)	±3°C	Internal	
Voltage	2.97 to 3.63V	±3%	Internal	
Bias Current	0 to 100mA	±10%	Internal	
TX Power	-5 to -1dBm	±3dB	Internal	
RX Power	-11.1 to -1dBm	±3dB	Internal	

Revision History

Revision	Initiated	Reviewed	Approved	DCN	Release Date
Version1.0	yangpeiyun	Sunbin	Dingzheng	New Released.	July 28, 2016
Version1.1	Tangzhiqiang	Yangpeiyun	Dingzheng	Update the new template.	Dec 19, 2019



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